

EAST - [lifetime killer.wsp:1]

File View Edit Tools Window Help

☐ Drafts
☒ ISNR:
☒ BRS:
☐ Pending
☒ Active
☒ L1: (606) (438/238) .CCLS.
☐ Failed
☒ Saved
☐ Favorites

DB: USPAT

☒ Highlight all hit terms initially

438/238

☒ BRST... ☒ ISAR... ☒ Image ☒ Text ☒ HTML

	U	I	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
9	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 5605853 A	19970225	9	Method of making a semiconductor device having	438/238	438/258; 438/586;
10	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 5506158 A	19960409	8	BiCMOS process with surface channel PMOS transistor	438/202	257/370; 257/379;
11	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 5489547 A	19960206	13	Method of fabricating semiconductor device having	438/238	148/DIG.136; 148/DIG.146;
12	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 5356826 A	19941018	11	Method of manufacturing semiconductor device	438/238	148/DIG.136; 438/253;
13	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 5187122 A	19930216	16	Process for fabricating an integrated circuit using	438/238	148/DIG.19; 257/532;
14	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 5013678 A	19910507	6	Method of making an integrated circuit	438/384	257/380; 438/238;
15	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 4419812 A	19831213	14	Method of fabricating an integrated circuit voltage	438/238	257/296; 257/379;
16	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 4416049 A	19831122	9	Semiconductor integrated circuit with vertical	438/238	257/380; 257/538;
17	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 4367580 A	19830111	6	Process for making polysilicon resistors	438/238	257/316; 257/380;
18	<input type="checkbox"/>	<input checked="" type="checkbox"/>	US 4208781 A	19800624	14	Semiconductor integrated circuit with implanted	438/238	29/610.1; 438/297;

[illegible]